Low-power buffer/line driver; 3-state

Rev. 1 — 20 March 2013

1. General description

The 74AUP1G125-Q100 provides a single non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (\overline{OE}). A HIGH level at pin \overline{OE} causes the output to assume a high-impedance OFF-state. This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input \overline{OE}) is HIGH.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A. Exceeds 5000 V
 - HBM JESD22-A114F Class 3A. Exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation



3. Ordering information

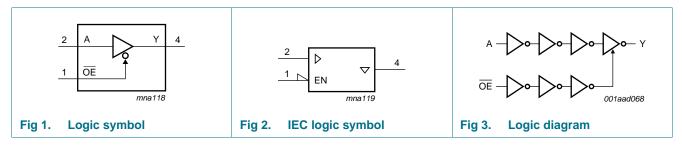
Table 1. Ordering information							
Type number	Package						
	Temperature range	Name	Description	Version			
74AUP1G125GW-Q100	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1			

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74AUP1G125GW-Q100	рМ

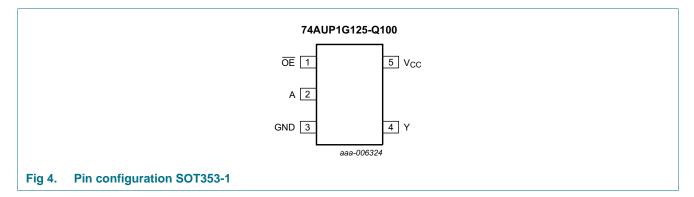
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



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6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
OE	1	output enable input
А	2	data input
GND	3	ground (0 V)
Y	4	data output
V _{CC}	5	supply voltage

7. Functional description

Table 4. Function table^[1]

Input OE		Output
OE	A	Y
L	L	L
L	Н	Н
н	Х	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

X = Don't care;

Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

			0	.0	,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode	<u>[1]</u> –0.5	V _{CC} + 0.5	V
		Power-down mode	<u>[1]</u> –0.5	+4.6	V
Ι _Ο	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = −40 °C to +125 °C	[2] _	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 package: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

Recommended operating conditions 9.

Table 6.	Recommended operating conditi	ons			
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 0.8 V \text{ to } 3.6 V$	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	S ℃					
VIH	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70 imes V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu A;$ V_{CC} = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_0 = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_0 = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_0 = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_0 = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3\times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V

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Low-power buffer/line driver; 3-state

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
l _{oz}	OFF-state output current		-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μΑ
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \ \text{to} \ 3.6 \ V \end{array}$	-	-	0.5	μA
∆l _{CC}	additional supply current	data input; V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	<u>[1]</u> -	-	40	μΑ
		$\overline{\text{OE}}$ input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	<u>[1]</u> -	-	110	μA
		all inputs; V _I = GND to 3.6 V; $\overline{OE} = V_{CC}$; V _{CC} = 0.8 V to 3.6 V	[2] _	-	1	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V_{I} = GND or V_{CC}	-	0.9	-	pF
Co	output capacitance					
	output enabled	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF
	output disabled	V_{CC} = 0 V to 3.6 V; V_{O} = GND or V_{CC}	-	1.5	-	pF
T _{amb} = –	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		V_{CC} = 0.9 V to 1.95 V	-	-	$0.35\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{ОН}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu\text{A};V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7\times V_{CC}$	-	-	V
		$I_{O} = -1.7$ mA; $V_{CC} = 1.4$ V	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.97	-	-	V
		I_O = -3.1 mA; V_{CC} = 2.3 V	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I_{O} = 1.1 mA; V_{CC} = 1.1 V	-	-	$0.3 \times V_{\text{CC}}$	V
		I_{O} = 1.7 mA; V_{CC} = 1.4 V	-	-	0.37	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.35	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.33	V
		I_{O} = 3.1 mA; V_{CC} = 2.3 V	-	-	0.45	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.33	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.45	V
1	input leakage current	$V_{\rm I}$ = GND to 3.6 V; $V_{\rm CC}$ = 0 V to 3.6 V	-	-	±0.5	μA
loz	OFF-state output current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 V \text{ to } 3.6 V; \\ V_{CC} = 0 V \text{ to } 3.6 V \end{array}$	-	-	±0.5	μA
OFF	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μΑ
Δl _{off}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
СС	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \text{ to } 3.6 \ V \end{array}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	data input; V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	<u>[1]</u> -	-	50	μA
		$\overline{\text{OE}}$ input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	<u>[1]</u> _	-	120	μΑ
		all inputs; V_1 = GND to 3.6 V; \overline{OE} = V_{CC} ; V_{CC} = 0.8 V to 3.6 V	[2] _	-	1	μA
T _{amb} = -	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 \text{ V} \text{ to } 1.95 \text{ V}$	$0.70 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
/ _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.25 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.30\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
√ _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu\text{A};$ V_{CC} = 0.8 V to 3.6 V	$V_{CC}-0.11$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6\times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V

Table 7. Static characteristics ...continued

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 $\mu A;$ V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		$I_0 = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	$0.33 \times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.41	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.39	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
I _I	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OZ}	OFF-state output current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 V \text{ to } 3.6 V; \\ V_{CC} = 0 V \text{ to } 3.6 V \end{array}$	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
ΔI_{CC}	additional supply current	data input; V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	<u>[1]</u> -	-	75	μΑ
		$\overline{\text{OE}}$ input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	<u>[1]</u> _	-	180	μΑ
		all inputs; $V_I = GND$ to 3.6 V; $\overline{OE} = V_{CC}$; $V_{CC} = 0.8$ V to 3.6 V	[2] _	-	1	μΑ

Table 7. Static characteristics ... continued

[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

[2] To show I_{CC} remains very low when the input-disable feature is enabled.

11. Dynamic characteristics

Dynamic characteristics Table 8.

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7

Symbol	Parameter	Conditions	Min	Тур <mark>[1]</mark>	Max	Unit
T _{amb} = 25	°C; C _L = 5 pF					
t _{pd}	propagation delay	A to Y; see Figure 5	[2]			
		$V_{CC} = 0.8 V$	-	20.6	-	ns
		V_{CC} = 1.1 V to 1.3 V	2.8	5.5	10.5	ns
		V_{CC} = 1.4 V to 1.6 V	2.2	3.9	6.1	ns
		V_{CC} = 1.65 V to 1.95 V	1.9	3.2	4.8	ns
		V_{CC} = 2.3 V to 2.7 V	1.6	2.6	3.6	ns
		V_{CC} = 3.0 V to 3.6 V	1.4	2.4	3.1	ns

Low-power buffer/line driver; 3-state

Table 8.	Dynamic	characteristics	continued
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Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7

Symbol	Parameter	Conditions	Min	Typ <mark>[1]</mark>	Max	Unit
t _{en}	enable time	OE to Y; see Figure 6	[3]			
		$V_{CC} = 0.8 V$	-	69.9	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.1	6.1	11.8	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	2.5	4.2	6.6	ns
		V_{CC} = 1.65 V to 1.95 V	2.1	3.4	5.1	ns
		V_{CC} = 2.3 V to 2.7 V	1.8	2.6	3.7	ns
		V_{CC} = 3.0 V to 3.6 V	1.7	2.4	3.1	ns
t _{dis}	disable time	OE to Y; see Figure 6	[4]			
		$V_{CC} = 0.8 V$	-	14.3	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	2.7	4.3	6.5	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	2.1	3.2	4.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.0	4.3	ns
		V_{CC} = 2.3 V to 2.7 V	1.4	2.2	2.9	ns
		V_{CC} = 3.0 V to 3.6 V	1.7	2.5	3.2	ns
T _{amb} = 25	°C; C _L = 10 pF					
propaga	propagation delay	A to Y; see Figure 5	[2]			
		$V_{CC} = 0.8 V$	-	24.0	-	ns
		V_{CC} = 1.1 V to 1.3 V	3.2	6.4	12.3	ns
		V_{CC} = 1.4 V to 1.6 V	2.1	4.5	7.3	ns
		V_{CC} = 1.65 V to 1.95 V	1.9	3.8	5.5	ns
		V_{CC} = 2.3 V to 2.7 V	2.1	3.2	4.2	ns
		V_{CC} = 3.0 V to 3.6 V	1.8	3.0	3.8	ns
t _{en}	enable time	OE to Y; see Figure 6	[3]			
		$V_{CC} = 0.8 V$	-	73.7	-	ns
		V_{CC} = 1.1 V to 1.3 V	3.6	6.9	13.5	ns
		V_{CC} = 1.4 V to 1.6 V	2.3	4.8	7.7	ns
		V_{CC} = 1.65 V to 1.95 V	2.0	3.9	5.8	ns
		V_{CC} = 2.3 V to 2.7 V	1.8	3.2	4.3	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	1.7	3.0	3.9	ns
t _{dis}	disable time	OE to Y; see Figure 6	<u>[4]</u>			
		$V_{CC} = 0.8 V$	-	32.7	-	ns
		V_{CC} = 1.1 V to 1.3 V	3.4	5.4	7.9	ns
		V_{CC} = 1.4 V to 1.6 V	2.2	4.1	5.5	ns
		V_{CC} = 1.65 V to 1.95 V	2.2	4.2	5.6	ns
		V_{CC} = 2.3 V to 2.7 V	1.7	3.0	3.8	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.1	3.8	4.8	ns

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Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Typ 🚺	Max	Unit
T _{amb} = 25	°C; C _L = 15 pF					
t _{pd}	propagation delay	A to Y; see Figure 5	[2]			
		$V_{CC} = 0.8 V$	-	27.4	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.6	7.2	14.1	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.0	5.1	8.1	ns
		V_{CC} = 1.65 V to 1.95 V	2.2	4.3	6.3	ns
		V_{CC} = 2.3 V to 2.7 V	2.0	3.7	4.9	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	3.5	4.4	ns
en	enable time	OE to Y; see Figure 6	[3]			
		$V_{CC} = 0.8 V$	-	77.5	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	4.0	7.7	15.2	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	3.0	5.3	8.4	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.3	4.4	6.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.1	3.6	5.0	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	3.5	4.5	ns
dis	disable time	OE to Y; see Figure 6	[4]			
		V _{CC} = 0.8 V	-	60.8	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	4.3	6.5	9.2	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	3.0	5.0	6.5	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.3	6.6	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.1	3.8	4.9	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.9	5.0	6.2	ns
Γ _{amb} = 25	°C; C _L = 30 pF					
pd	propagation delay	A to Y; see Figure 5	[2]			
-		$V_{CC} = 0.8 V$	-	37.4	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.5	19.0	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	4.0	6.7	10.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.6	8.4	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.7	4.8	6.3	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.7	4.6	5.8	ns
en	enable time	OE to Y; see Figure 6	[3]			
		$V_{CC} = 0.8 V$	-	88.9	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.2	9.9	19.8	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	4.0	6.8	10.8	ns
		$V_{CC} = 1.65$ V to 1.95 V	3.0	5.6	8.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.7	4.8	6.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.7	4.6	6.0	ns

Table 8. Dynamic characteristics ...continued

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Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Typ 1	Max	Unit
t _{dis}	disable time	OE to Y; see Figure 6	<u>[4]</u>			
		$V_{CC} = 0.8 V$	-	49.9	-	ns
		V_{CC} = 1.1 V to 1.3 V	6.0	9.9	13.3	ns
		V_{CC} = 1.4 V to 1.6 V	4.4	7.7	9.6	ns
		V_{CC} = 1.65 V to 1.95 V	5.1	8.7	11.1	ns
		V_{CC} = 2.3 V to 2.7 V	3.6	6.2	7.4	ns
		V_{CC} = 3.0 V to 3.6 V	5.2	8.7	10.5	ns
T _{amb} = 2	5 °C					
C _{PD}	power dissipation capacitance	f = 1 MHz; V_I = GND to V_{CC}	[5]			
		output enabled				
		$V_{CC} = 0.8 V$	-	2.7	-	pF
		V_{CC} = 1.1 V to 1.3 V	-	2.8	-	pF
		V_{CC} = 1.4 V to 1.6 V	-	2.9	-	pF
		V_{CC} = 1.65 V to 1.95 V	-	3.0	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	3.6	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$				pF

Table 8. Dynamic characteristics ...continued

[1] All typical values are measured at nominal V_{CC}.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

 $[3] \quad t_{en} \mbox{ is the same as } t_{PZH} \mbox{ and } t_{PZL}.$

 $[4] \quad t_{\text{dis}} \text{ is the same as } t_{\text{PHZ}} \text{ and } t_{\text{PLZ}}.$

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7

Symbol	Parameter	Conditions		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			-		Max	Min	Max	
$C_L = 5 pF$								
t _{pd}	propagation delay	A to Y; see Figure 5	[1]					
		V_{CC} = 1.1 V to 1.3 V		2.5	11.7	2.5	12.9	ns
		V_{CC} = 1.4 V to 1.6 V		2.0	7.3	2.0	8.1	ns
		V_{CC} = 1.65 V to 1.95 V		1.7	6.1	1.7	6.7	ns
		V_{CC} = 2.3 V to 2.7 V		1.4	4.3	1.4	4.9	ns
		V_{CC} = 3.0 V to 3.6 V		1.2	3.9	1.2	4.4	ns

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		–40 °C t	–40 °C to +85 °C		–40 °C to +125 °C	
				Min	Max	Min	Max	
t _{en}	enable time	OE to Y; see Figure 6	[2]					
		V_{CC} = 1.1 V to 1.3 V		2.9	13.9	2.9	15.4	ns
		V_{CC} = 1.4 V to 1.6 V		2.3	7.7	2.3	8.3	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	6.2	2.0	6.8	ns
		V_{CC} = 2.3 V to 2.7 V		1.7	4.5	1.7	5.0	ns
		V_{CC} = 3.0 V to 3.6 V		1.7	3.5	1.7	3.9	ns
t _{dis}	disable time	OE to Y; see Figure 6	[3]					
		V_{CC} = 1.1 V to 1.3 V		2.7	7.3	2.7	8.2	ns
		V_{CC} = 1.4 V to 1.6 V		2.1	5.1	2.1	5.7	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	5.0	2.0	5.7	ns
		V_{CC} = 2.3 V to 2.7 V		1.4	3.3	1.4	4.1	ns
		V_{CC} = 3.0 V to 3.6 V		1.7	3.4	1.7	3.9	ns
C _L = 10 p	F							
t _{pd} propagati	propagation delay	A to Y; see Figure 5	<u>[1]</u>					
		V_{CC} = 1.1 V to 1.3 V		3.0	13.8	3.0	15.2	ns
		V_{CC} = 1.4 V to 1.6 V		1.9	8.5	1.9	9.4	ns
		V_{CC} = 1.65 V to 1.95 V		1.7	6.8	1.7	7.6	ns
		V_{CC} = 2.3 V to 2.7 V		1.6	5.3	1.6	5.9	ns
		V_{CC} = 3.0 V to 3.6 V		1.6	4.6	1.6	5.2	ns
t _{en}	enable time	OE to Y; see Figure 6	[2]					
		V_{CC} = 1.1 V to 1.3 V		3.4	15.8	3.4	17.5	ns
		V_{CC} = 1.4 V to 1.6 V		2.2	8.6	2.2	9.4	ns
		V_{CC} = 1.65 V to 1.95 V		1.9	6.8	1.9	7.4	ns
		$V_{\rm CC}$ = 2.3 V to 2.7 V		1.7	5.3	1.7	5.9	ns
		V_{CC} = 3.0 V to 3.6 V		1.7	4.3	1.7	4.8	ns
t _{dis}	disable time	OE to Y; see Figure 6	<u>[3]</u>					
		V_{CC} = 1.1 V to 1.3 V		3.4	8.8	3.4	9.9	ns
		V_{CC} = 1.4 V to 1.6 V		2.2	6.2	2.2	7.1	ns
		V_{CC} = 1.65 V to 1.95 V		1.9	6.3	1.9	7.1	ns
		V_{CC} = 2.3 V to 2.7 V		1.7	4.5	1.7	5.1	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	5.0	1.7	5.6	ns
C _L = 15 p	F							
t _{pd}	propagation delay	A to Y; see Figure 5	<u>[1]</u>					
		V_{CC} = 1.1 V to 1.3 V		3.3	15.8	3.3	17.5	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.5	9.8	2.5	10.9	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	7.9	2.0	8.8	ns
		V_{CC} = 2.3 V to 2.7 V		1.8	6.0	1.8	6.7	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.8	5.4	1.8	6.1	ns

Table 9. Dynamic characteristics ... continued

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Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		–40 °C t	o +85 °C	–40 °C to +125 °C		Unit
				Min	Max	Min	Max	
en	enable time	OE to Y; see Figure 6	[2]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.7	17.6	3.7	19.6	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.5	9.8	2.5	10.7	ns
		V_{CC} = 1.65 V to 1.95 V		2.1	7.7	2.1	8.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.0	6.1	2.0	6.8	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.9	4.9	1.9	5.5	ns
dis	disable time	OE to Y; see Figure 6	[3]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.7	10.3	3.7	11.6	ns
		V_{CC} = 1.4 V to 1.6 V		2.5	7.4	2.5	8.4	ns
		V_{CC} = 1.65 V to 1.95 V		2.1	7.4	2.1	8.9	ns
		V_{CC} = 2.3 V to 2.7 V		2.0	5.1	2.0	6.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.9	6.6	1.9	7.4	ns
C _L = 30 p	F							
t _{pd}	propagation delay	A to Y; see Figure 5	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.4	21.6	4.4	24.0	ns
		V_{CC} = 1.4 V to 1.6 V		3.0	13.0	3.0	14.5	ns
		V_{CC} = 1.65 V to 1.95 V		2.6	10.3	2.6	11.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.5	7.8	2.5	8.7	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.5	7.5	2.5	8.3	ns
en	enable time	OE to Y; see Figure 6	[2]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.8	22.8	4.8	25.3	ns
		V_{CC} = 1.4 V to 1.6 V		3.1	12.6	3.1	14.1	ns
		V_{CC} = 1.65 V to 1.95 V		2.8	10.2	2.8	11.3	ns
		V_{CC} = 2.3 V to 2.7 V		2.6	7.8	2.6	8.8	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.6	6.9	2.6	7.7	ns
dis	disable time	OE to Y; see Figure 6	<u>[3]</u>					
		V_{CC} = 1.1 V to 1.3 V		4.8	14.8	4.8	16.5	ns
		V_{CC} = 1.4 V to 1.6 V		3.1	10.7	3.1	12.1	ns
		V_{CC} = 1.65 V to 1.95 V		2.8	12.4	2.8	13.8	ns
		V_{CC} = 2.3 V to 2.7 V		2.6	8.6	2.6	9.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.6	10.8	2.6	13.1	ns

Table 9. Dynamic characteristics ...continued

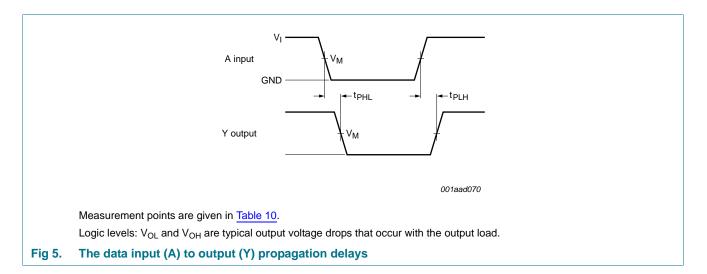
Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 7</u>

 $\label{eq:tpd} [1] \quad t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}.$

 $[3] \quad t_{dis} \mbox{ is the same as } t_{PHZ} \mbox{ and } t_{PLZ}.$

Low-power buffer/line driver; 3-state

12. Waveforms



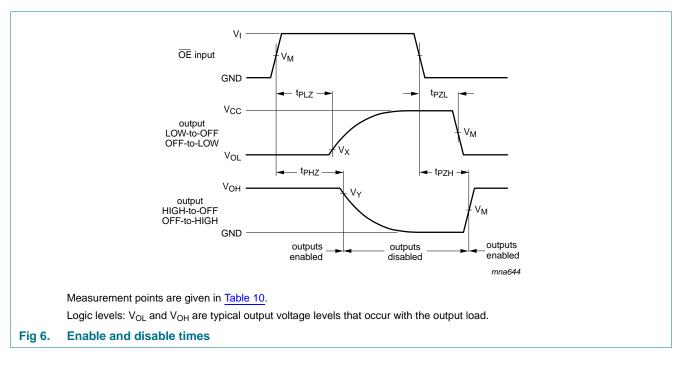


Table 10. Measurement points

Supply voltage	Input			Output		
V _{CC}	VM	Vi	$\mathbf{t}_{r} = \mathbf{t}_{f}$	V _M	V _X	V _Y
0.8 V to 1.6 V	$0.5\times V_{CC}$	V _{CC}	\leq 3.0 ns	$0.5\times V_{CC}$	$V_{OL} + 0.1 \ V$	$V_{OH} - 0.1 \ V$
1.65 V to 2.7 V	$0.5\times V_{CC}$	V _{CC}	\leq 3.0 ns	$0.5\times V_{CC}$	$V_{OL} + 0.15 \ V$	V _{OH} – 0.15 V
3.0 V to 3.6 V	$0.5\times V_{CC}$	V _{CC}	\leq 3.0 ns	$0.5\times V_{CC}$	$V_{OL} + 0.3 \ V$	$V_{OH} - 0.3 \ V$

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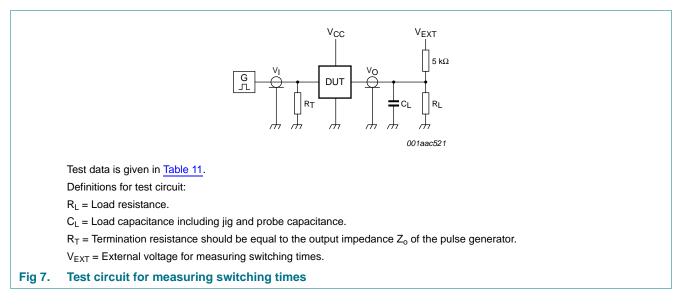


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.

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13. Package outline

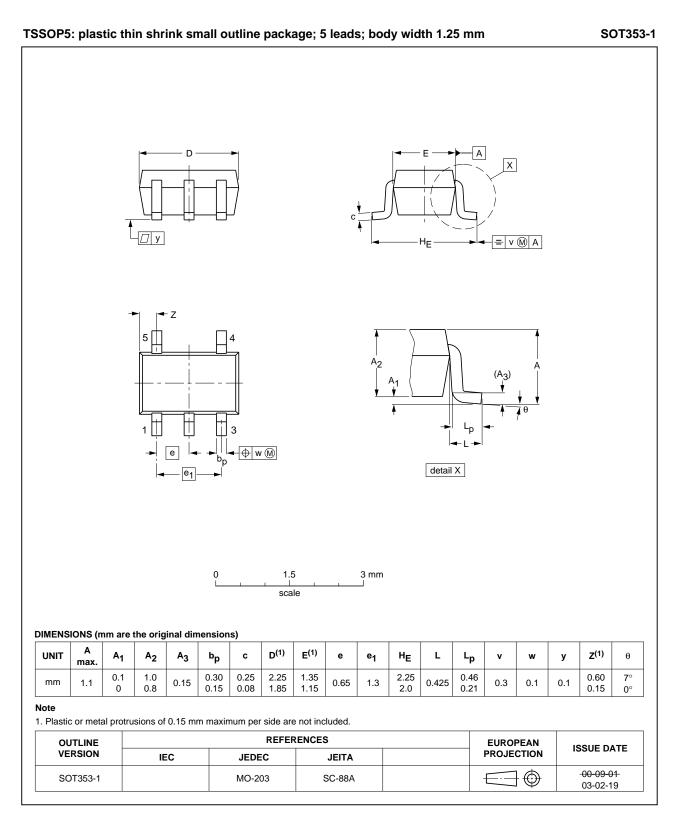


Fig 8. Package outline SOT353-1 (TSSOP5)

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14. Abbreviations

Table 12. A	bbreviations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model

15. Revision history

Table 13. Revision his	tory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G125_Q100 v.1	20130320	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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